Programmable Logic Devices

CS211 Chapter B

James YU yujq3@sustech.edu.cn

Department of Computer Science and Engineering Southern University of Science and Technology

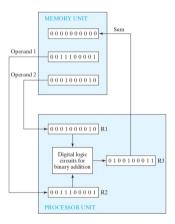
Jul. 22, 2021



Memory



• A memory unit is a device to which binary information is transferred for storage and from which information is retrieved when needed.



Memory

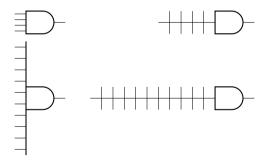


- A memory unit is a collection of cells capable of storing a large quantities of binary information
 - Random access memory (RAM)
 - Performs both read and write operations.
 - Read-only memory (ROM)
 - Only read operation, information cannot be altered by writing.
 - Is a programmable logic device (PLD).
 - Information storage in some fashion and embedded within hardware, called programming the device.

Memory



- PLD has many types, ROM is one.
 - Others are Programmable Array Logic (PAL), Programmable Logic Array (PLA), and the field-programmable gate array (FPGA).
 - An integrated circuit, internal logic gates connected through electronic paths similar to fuses.
 - May have hundreds to millions of gates, thus requires a special gate symbology:

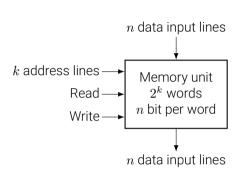




- A memory unit is a collection of storage cells with associated circuits needed.
 - Information can be selectively retrieved from any of its internal locations.
 - Information retrieval time at any random location is the same, therefore *Random-Access* memory.
- Binary information stored are grouped in words.
 - Words are the unit of moving in and out of storage.
 - (Recall) 8 bits = 1 byte.
 - Most computer memory has words multiple of 8 bits/1 byte in length.

有分科技大学 SOUTHERN UNIVERSITY OF SCIENCE AND TECHNOLOGY

- Communication achieved through:
 - Data input and output lines.
 - Address selection lines.
 - Control lines.
- To have *n* bits in a word.
 - n lines for input/output
- To have m words.
 - k lines for address, such that $m \leq 2^k$.



有分科技大学 SOUTHERN UNIVERSITY OF SCIENCE AND TECHNOLOGY

- Each word in the memory is assigned a unique address from 0 to 2^k-1.
- An internal decoder: k lines to 2^k addresses.
- On the right is 1K words of 16 bits.

Memory address

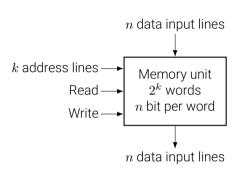
Binary	Decimal
0000000000	0
0000000001	1
0000000010	2
	i
1111111101	1021
1111111110	1022
1111111111	1023

Memory content

1011010101011101
1010101110001001
0000110101000110
÷
1001110100010100
0000110100011110
1101111000100101

有方科技大学 SOUTHERN UNIVERSITY OF SCIENCE AND TECHNOLOGY

- Two operations of RAM: read and write.
- Write
 - Apply binary address to address lines;
 - Apply data bits to data input lines;
 - Activate the write input
- Read
 - Apply binary address to address lines;
 - Activate the read input;





- Commercial memory components:
 - One input selects the unit.
 - The other determines the operation.

Memory Enable	Read/Write	Memory Operation
0	X	None
1	0	Write to selected word
1	1	Read from selected word

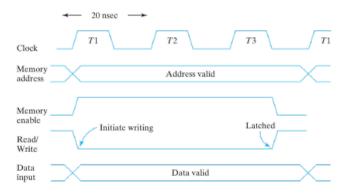


- Memory unit operation is controlled by an external device, e.g., CPU, synchronized by its own clock.
 - Memory does not employ an internal clock.
 - Access time: time required to select a word and read it.
 - Cycle time: complete a write operation.
 - CPU provide memory control signals to synchronize.
 - Access/Cycle time within a time equal to a fixed number of CPU clock cycles.



10 / 32

- CPU: 50MHz one clock cycle = 20ns
- Memory: access time = cycle time = 50ns
 - These times not always equal.

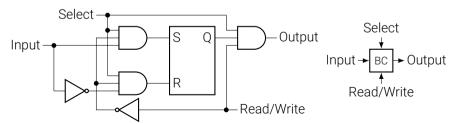




- Integrated circuit RAM units available in two operating modes:
- Static RAM: essentially latches, available as long as powered.
 - Easier to use, has shorter read/write cycles.
- Dynamic RAM: information stored in the form of electric charges on capacitors, discharge over time.
 - Capacitors periodically recharged by refreshing the memory.
 - Reduced power consumption and larger storage capacity
- Memory units that lose stored information when power is turned off are *volatile*.
- Non-volatile memories retained information with magnetic components.
 - Data represented by direction of magnetization.

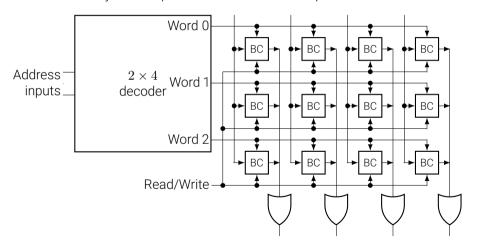


- To require storage components in a memory unit, a decoding circuit is required:
 - Select memory word specified by input address
- m words with n bits each consist of $m \times n$ binary storage cells as the basic building blocks.
- Modeled by an SR latch with external gates to form a D latch.
 - Actual cells are circuits with 4 to 6 transistors.
 - Convenient to model it with logic symbols





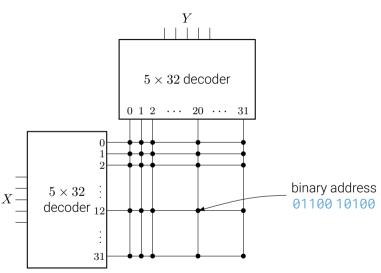
- A binary storage cell must be very small.
 - Pack as many cells as possible in the small IC chip.





- Commercial RAMs have a capacity of thousands of words, each 1 to 64 bits
- k to 2^k decoder requires 2^k AND gates with k inputs.
 - Can be reduced by employing two decoders: coincident decoding.
 - One decoder performs row selection, the other column selection

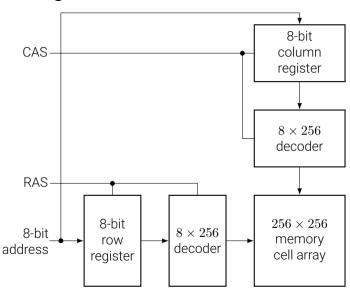






- SRAM: typically 6 transistors
- DRAM: a MOS transistor + a capacitor
 - Four times the density of SRAM.
 - Preferred technology for large memories.
- Address decoding for DRAM is in two-dimensional array, larger memories have multiple arrays.
- Address multiplexing is used to reduce the number of pins in the IC package.
 - The same set of pins used for row and column selection.





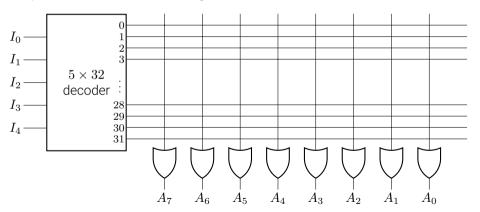


- ROM is a memory device in which permanent binary information is stored.
- Once the pattern is established, stays within the unit even when power is turned off.





- Consider a 32 × 8 ROM:
- Five input lines for address.
- 32 input connections and 8 OR gates = 256 internal connections.





- These intersections are programmable:
 - Logically equivalent to a switch that can be closed (connected) or open (disconnected).
 - Also called *crosspoints*.
- One of the simplest technology employs a fuse.
 - Normally connects the two points.
 - Opened or "blown" by high-voltage pulse into the fuse.

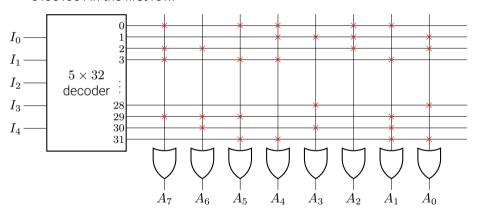


- Internal binary storage of a ROM specified by a truth table.
 - Each address stores a word of 8 bits.

Inputs							Out	puts				
$\overline{I_4}$	I_3	I_2	I_1	$\overline{I_0}$	$\overline{A_7}$	A_6	A_5	A_4	A_3	A_2	A_1	$\overline{A_0}$
0	0	0	0	0	0	1	0	0	1	0	0	1
0	0	0	0	1	1	1	1	0	0	0	1	0
0	0	0	1	0	0	0	1	1	1	0	1	0
0	0	0	1	1	0	1	0	0	1	1	0	1
									•			
1	1	1	0	0	1	1	1	1	0	1	1	0
1	1	1	0	1	0	0	0	1	1	1	0	1
1	1	1	1	0	1	0	1	1	0	1	0	1
1	1	1	1	1	1	1	0	0	1	1	0	0

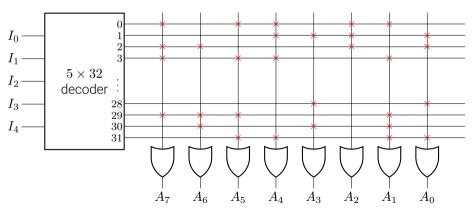


- Program the ROM: blows fuse links in accordance with the truth table
 - 01001001 in the first row.





- Combinational circuit
 - (Recall) Decoder: k input = 2^k minterms.
 - By choosing connections for those minterms.
 - For example, eight functions of five binary inputs.



Example



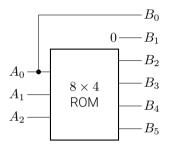
- Design a combinational circuit using a ROM. The circuit accepts a three-bit number and outputs a binary number equal to the square of the input number.
 - $B_0 \equiv A_0$, $B_1 \equiv 0$, no need to generate.

Inputs			Outputs						Decimal
$\overline{A_2}$	A_1	$\overline{A_0}$	$\overline{B_5}$	B_4	B_3	B_2	B_1	B_0	Decimal
0	0	0	0	0	0	0	0	0	0
0	0	1	0	0	0	0	0	1	1
0	1	0	0	0	0	1	0	0	4
0	1	1	0	0	1	0	0	1	9
1	0	0	0	1	0	0	0	0	16
1	0	1	0	1	1	0	0	1	25
1	1	0	1	0	0	1	0	0	36
1	1	1	1	1	0	0	0	1	49

Example



• 3 inputs, 4 outputs: 8×4 ROM.



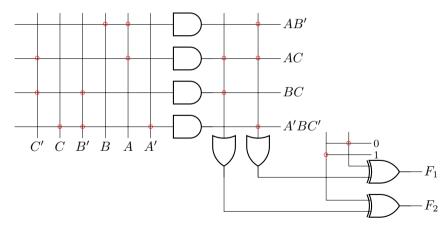
-	Inputs	S	Outputs				
$\overline{A_2}$	A_1	$\overline{A_0}$	$\overline{B_5}$	B_4	B_3	B_2	
0	0	0	0	0	0	0	
0	0	1	0	0	0	0	
0	1	0	0	0	0	1	
0	1	1	0	0	1	0	
1	0	0	0	1	0	0	
1	0	1	0	1	1	0	
1	1	0	1	0	0	1	
1	1	1	1	1	0	0	



- A programmable ROM is a kind of combinational programmable logic device (PLD) with fixed AND array (decoder) and programmable OR array.
- Others are programmable array logic (PAL) with programmable AND array and fixed OR array,
- and programmable logic array (PLA) with programmable AND and OR arrays.
 - Name emerged from different vendors during the development of PLD.

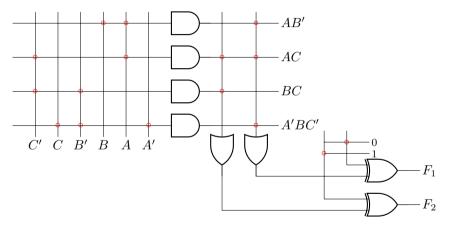


- Similar to PROM, but no full decoding of variables, i.e., not all minterms.
- Decoder replaced by an array of AND gates.



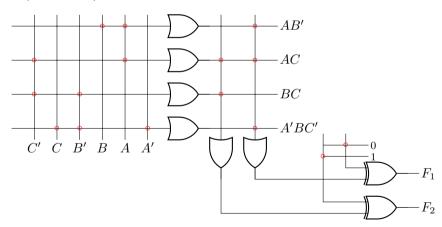


• XOR receive logic 0 or 1: complement on 1.





- $F_1 = AB' + AC + A'BC'$
- $F_2 = (AC + BC)'$





- $F_1 = AB' + AC + A'BC'$
- $F_2 = (AC + BC)'$
- Fuse map can be specified in a tabular form.

		I	Inputs			puts (C)
	Product Term	\overline{A}	B	\overline{C}	$\overline{F_1}$	$\overline{F_2}$
AB'	1	1	0	_	1	_
AC	2	1	_	1	1	1
BC	3	_	1	1	_	1
A'BC'	4	0	1	0	1	_



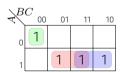
- Size of a PLA is specified by the number of inputs, product terms, and outputs.
 - Typically have 16 inputs, 48 product terms, 8 outputs.
- For *n* inputs, *k* products, *m* outputs:
 - n buffer-inverter gates;
 - k AND gates;
 - m OR gates, and m XOR gates;
 - $2n \times k$ connections between inputs and AND array;
 - $k \times m$ connections between AND and OR arrays;
 - m connections associated with XOR gates.

Example



- Implement the following two Boolean functions with a PLA:
 - $F_1(A, B, C) = \sum (0, 1, 2, 4) = (AB + AC + BC)'$.
 - $F_2(A, B, C) = \sum_{i=0}^{\infty} (0, 5, 6, 7) = AB + AC + A'B'C'$.





		I	Inputs			puts (C)
	Product Term				$\frac{\cdot}{F_1}$	F_2
\overline{AB}	1	1	1	_	1	1
AC	1	1	-	1	1	1
BC	1	_	1	1	1	_
A'B'C'	1	0	0	0	0	1